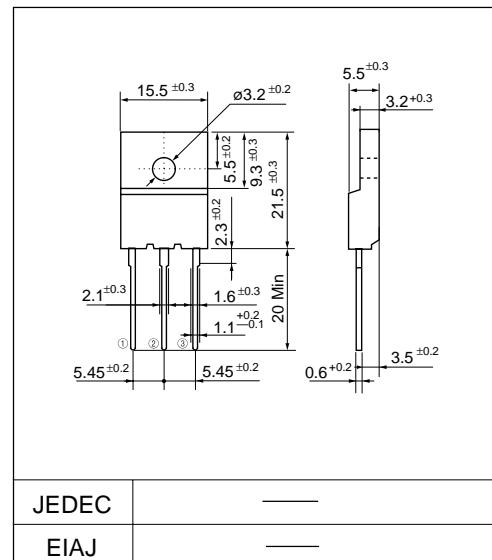


ESAD83M-006R (30A)

(60V / 30A)

SCHOTTKY BARRIER DIODE

■ Outline drawings, mm



■ Features

- Insulated package by fully molding
- Low VF
- Super high speed switching
- High reliability by planer design

■ Applications

- High speed power switching

■ Maximum ratings and characteristics

● Absolute maximum ratings

Item	Symbol	Conditions	Ratings	Unit
Repetitive peak reverse voltage	V _{RRM}		60	V
Non-repetitive peak reverse voltage	V _{RSM}	t _w =500ns, duty=1/40	60	V
Isolating voltage	V _{iso}	Terminals-to-case, AC. 1min.	1500	V
Average output current	I _o	Square wave, duty=1/2 T _c =106°C	30*	A
Surge current	I _{FSM}	Sine wave 10ms	200	A
Operating junction temperature	T _j		-40 to +150	°C
Storage temperature	T _{stg}		-40 to +150	°C

* Average forward current of centertap full wave connection

● Electrical characteristics (Ta=25°C Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _{FM}	I _{FM} =12.5A	0.58	V
Reverse current	I _{RRM}	V _R =V _{RRM}	20	mA
Thermal resistance	R _{th(j-c)}	Junction to case	1.7	°C/W

■ Characteristics

